



SamHop Microelectronics Corp.

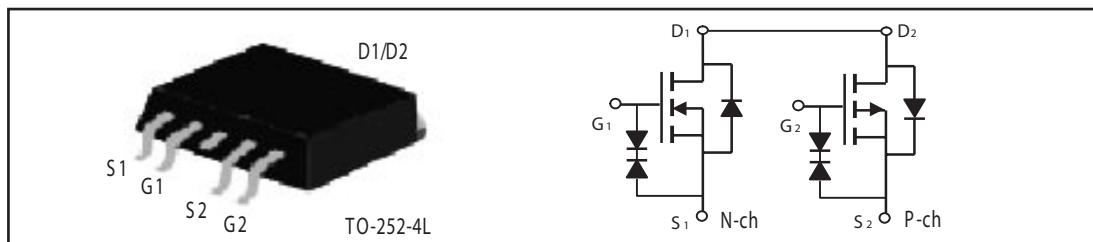
STU310DH

May,28,2007

Dual Enhancement Mode Field Effect Transistor (N and P Channel)

| PRODUCT SUMMARY (N-Channel) | | |
|-----------------------------|----------------|----------------------------------|
| V _{DSS} | I _D | R _{D(S(ON))} (mΩ) Max |
| 30V | 19A | 20 @ V _{GS} = 10V |
| | | 28 @ V _{GS} = 4.5V |

| PRODUCT SUMMARY (P-Channel) | | |
|-----------------------------|----------------|----------------------------------|
| V _{DSS} | I _D | R _{D(S(ON))} (mΩ) Max |
| -30V | -15A | 30 @ V _{GS} = -10V |
| | | 44 @ V _{GS} = -4.5V |

ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

| Parameter | Symbol | N-Channel | P-Channel | Unit |
|--|-----------------------------------|------------------------|-----------|------|
| Drain-Source Voltage | V _{DSS} | 30 | -30 | V |
| Gate-Source Voltage | V _{GS} | ±20 | ±20 | V |
| Drain Current-Continuous @ T _c | I _D | 25 °C | 19 | A |
| | | 70 °C | 17 | A |
| -Pulsed ^a | I _{DM} | 50 | -50 | A |
| Drain-Source Diode Forward Current | I _S | 10 | -6 | A |
| Maximum Power Dissipation | P _D | T _c = 25 °C | 11 | W |
| | | T _c = 70 °C | 7.7 | |
| Operating Junction and Storage Temperature Range | T _J , T _{STG} | -55 to 175 | | °C |

THERMAL CHARACTERISTICS

| | | | |
|---|------------------|------|------|
| Thermal Resistance, Junction-to-Case | R _{θJC} | 13.6 | °C/W |
| Thermal Resistance, Junction-to-Ambient | R _{θJA} | 120 | °C/W |

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N-Channel ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ ^c | Max | Unit |
|---|---------------------|--|-----|------------------|----------|----------------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS} = 0V, I_D = 250\mu A$ | 30 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 24V, V_{GS} = 0V$ | | | 1 | μA |
| Gate-Body Leakage | I_{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | | | ± 10 | μA |
| ON CHARACTERISTICS ^a | | | | | | |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = 250\mu A$ | 1 | 1.8 | 3 | V |
| Drain-Source On-State Resistance | $R_{DS(\text{ON})}$ | $V_{GS} = 10V, I_D = 10A$ | | 14 | 20 | $m\text{ ohm}$ |
| | | $V_{GS} = 4.5V, I_D = 8A$ | | 20 | 28 | $m\text{ ohm}$ |
| On-State Drain Current | $I_{D(\text{ON})}$ | $V_{DS} = 5V, V_{GS} = 4.5V$ | 20 | | | A |
| Forward Transconductance | g_F | $V_{DS} = 10V, I_D = 10A$ | | 16.5 | | S |
| DYNAMIC CHARACTERISTICS ^b | | | | | | |
| Input Capacitance | C_{ISS} | $V_{DS} = 15V, V_{GS} = 0V$ $f = 1.0\text{MHz}$ | | 635 | | pF |
| Output Capacitance | C_{OSS} | | | 170 | | pF |
| Reverse Transfer Capacitance | C_{RSS} | | | 97 | | pF |
| SWITCHING CHARACTERISTICS ^b | | | | | | |
| Turn-On Delay Time | $t_{D(\text{ON})}$ | $V_{DD} = 15V$ $I_D = 1 A$ $V_{GS} = 10V$ $R_{GEN} = 6 \text{ ohm}$ | | 12.5 | | ns |
| Rise Time | t_r | | | 12 | | ns |
| Turn-Off Delay Time | $t_{D(\text{OFF})}$ | | | 45 | | ns |
| Fall Time | t_f | | | 10 | | ns |
| Total Gate Charge | Q_g | $V_{DS} = 15V, I_D = 20A, V_{GS} = 10V$ | | 12 | | nC |
| | | $V_{DS} = 15V, I_D = 20A, V_{GS} = 4.5V$ | | 6 | | nC |
| Gate-Source Charge | Q_{gs} | $V_{DS} = 15V, I_D = 20 A$ $V_{GS} = 10V$ | | 1.8 | | nC |
| Gate-Drain Charge | Q_{gd} | | | 3.5 | | nC |

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P-Channel ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ ^c | Max | Unit |
|---|---------------------|---|-----|------------------|----------|----------------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS} = 0V, I_D = -250\mu A$ | -30 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = -24V, V_{GS} = 0V$ | | | -1 | μA |
| Gate-Body Leakage | I_{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | | | ± 10 | μA |
| ON CHARACTERISTICS ^a | | | | | | |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = -250\mu A$ | -1 | -1.8 | -3 | V |
| Drain-Source On-State Resistance | $R_{DS(\text{ON})}$ | $V_{GS} = -10V, I_D = -6A$ | | 24 | 30 | $m\text{ ohm}$ |
| | | $V_{GS} = -4.5V, I_D = -4A$ | | 35 | 44 | $m\text{ ohm}$ |
| On-State Drain Current | $I_{D(\text{ON})}$ | $V_{DS} = -5V, V_{GS} = -10V$ | -20 | | | A |
| Forward Transconductance | g_F | $V_{DS} = -10V, I_D = -6A$ | | 12.5 | | S |
| DYNAMIC CHARACTERISTICS ^b | | | | | | |
| Input Capacitance | C_{ISS} | $V_{DS} = -15V, V_{GS} = 0V$ $f = 1.0\text{MHz}$ | | 1120 | | pF |
| Output Capacitance | C_{OSS} | | | 280 | | pF |
| Reverse Transfer Capacitance | C_{RSS} | | | 190 | | pF |
| SWITCHING CHARACTERISTICS ^b | | | | | | |
| Turn-On Delay Time | $t_{D(\text{ON})}$ | $V_{DD} = -15V$ $I_D = -1A$ $V_{GS} = -10V$ $R_{GEN} = 6\text{ ohm}$ | | 15 | | ns |
| Rise Time | t_r | | | 28 | | ns |
| Turn-Off Delay Time | $t_{D(\text{OFF})}$ | | | 110 | | ns |
| Fall Time | t_f | | | 30 | | ns |
| Total Gate Charge | Q_g | $V_{DS} = -15V, I_D = -20A, V_{GS} = -10V$ | | 22 | | nC |
| | | $V_{DS} = -15V, I_D = -20A, V_{GS} = -4.5V$ | | 10.5 | | nC |
| Gate-Source Charge | Q_{gs} | $V_{DS} = -15V, I_D = -20A$ $V_{GS} = -10V$ | | 2.5 | | nC |
| Gate-Drain Charge | Q_{gd} | | | 6.5 | | nC |

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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ ^c | Max | Unit |
|---|----------|--|------|------------------|-------------|-------------|
| DRAIN-SOURCE DIODE CHARACTERISTICS ^b | | | | | | |
| Diode Forward Voltage | V_{SD} | $V_{GS} = 0\text{V}, I_S = 10\text{A}$ $V_{GS} = 0\text{V}, I_S = -6\text{A}$ | N-Ch | | 0.9 -0.9 | 1.3 -1.3 |
| | | | P-Ch | | | V |

Notes

a.Pulse Test:Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2\%$.

b.Guaranteed by design, not subject to production testing.

N-Channel

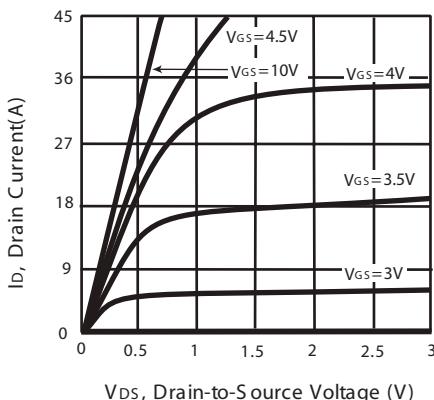


Figure 1. Output Characteristics

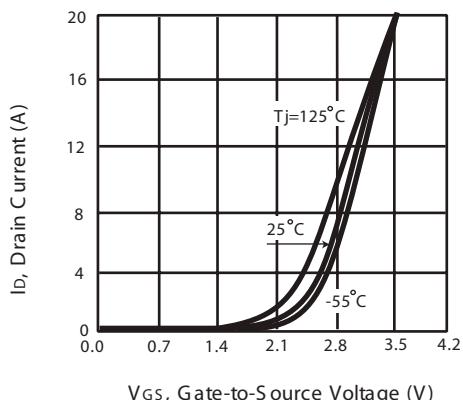


Figure 2. Transfer Characteristics

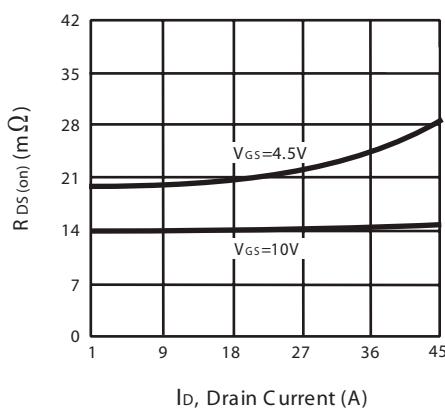


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

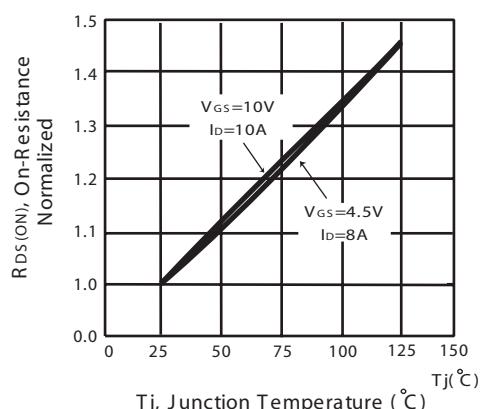
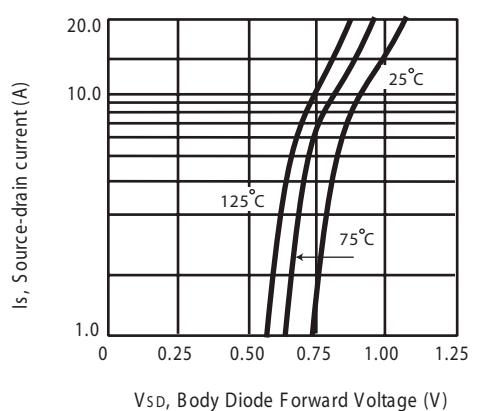
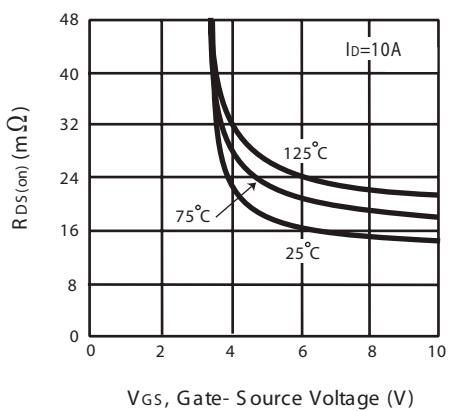
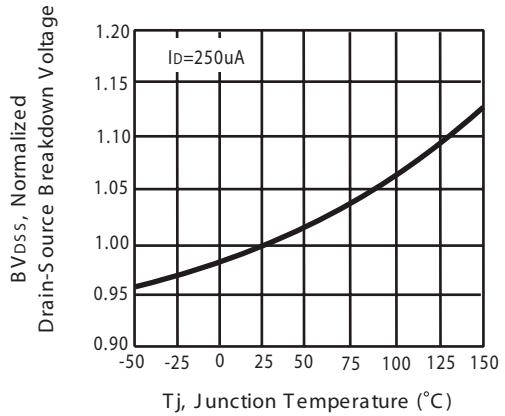
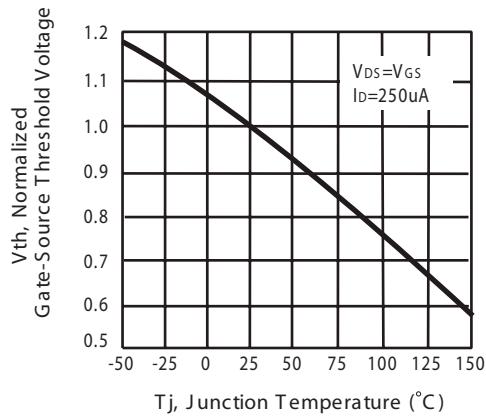


Figure 4. On-Resistance Variation with Drain Current and Temperature

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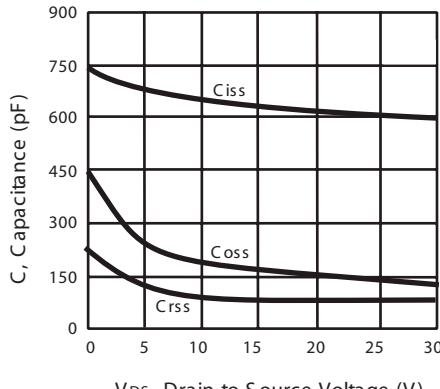


Figure 10. Capacitance

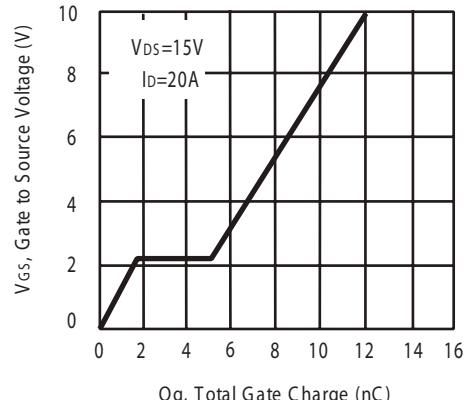


Figure 11. Gate Charge

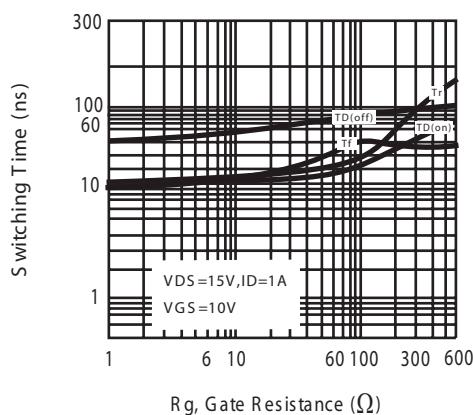


Figure 12. switching characteristics

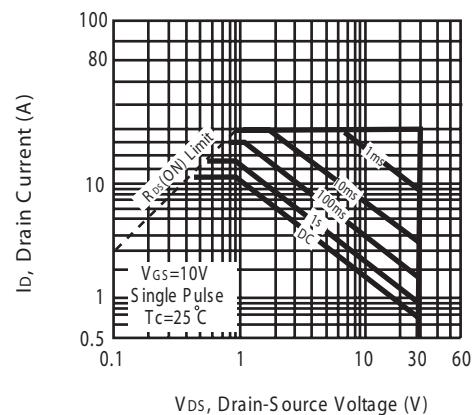


Figure 13. Maximum Safe Operating Area

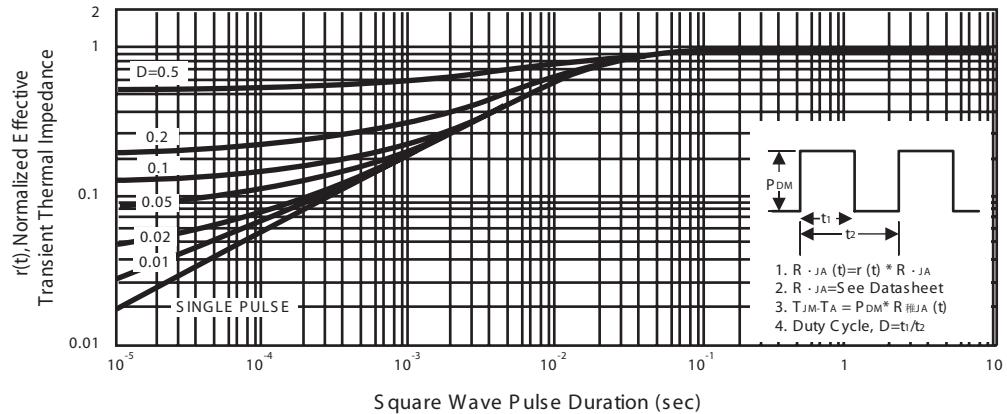


Figure 14. Normalized Thermal Transient Impedance Curve

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P-Channel

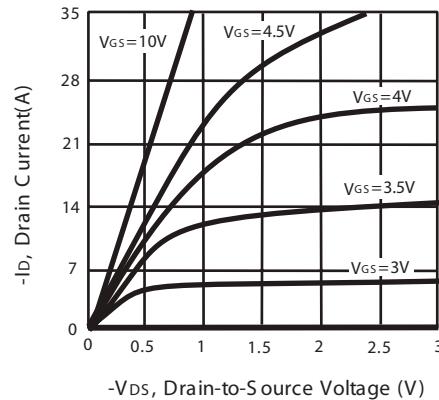


Figure 1. Output Characteristics

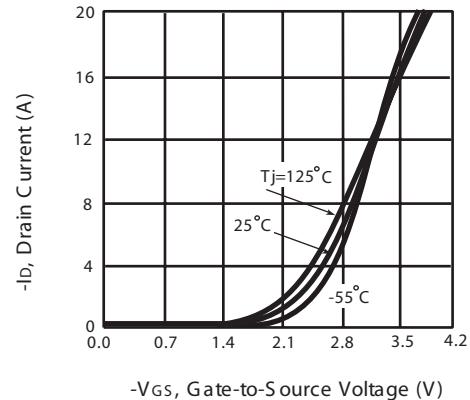


Figure 2. Transfer Characteristics

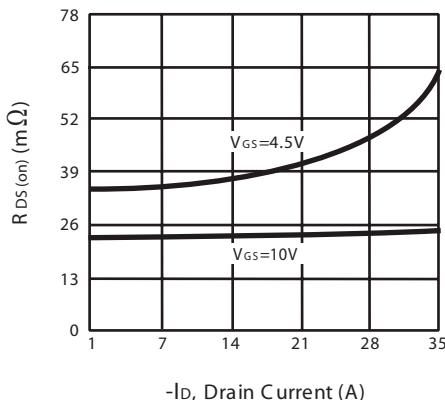


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

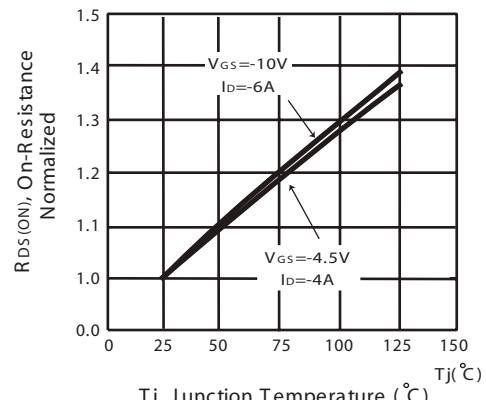


Figure 4. On-Resistance Variation with Drain Current and Temperature

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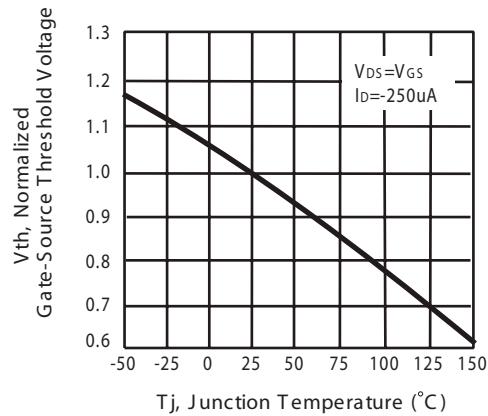


Figure 5. Gate Threshold Variation with Temperature

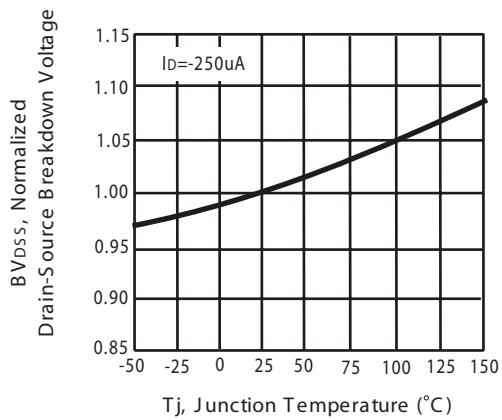


Figure 6. Breakdown Voltage Variation with Temperature

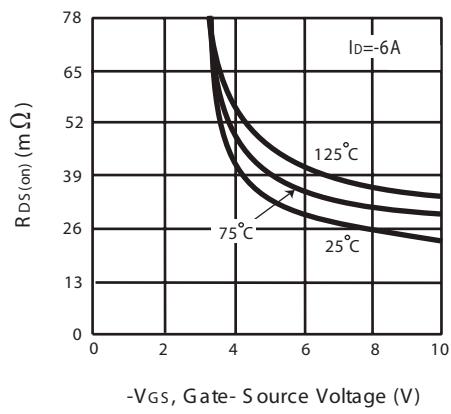


Figure 7. On-Resistance vs. Gate-Source Voltage

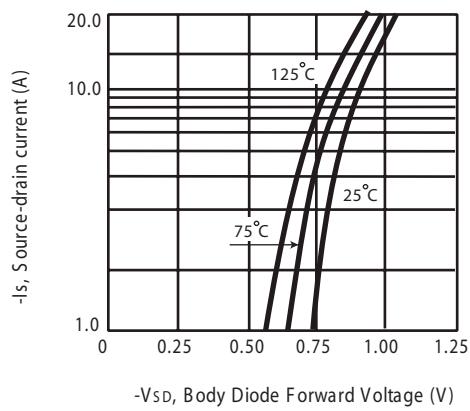


Figure 8. Body Diode Forward Voltage Variation with Source Current

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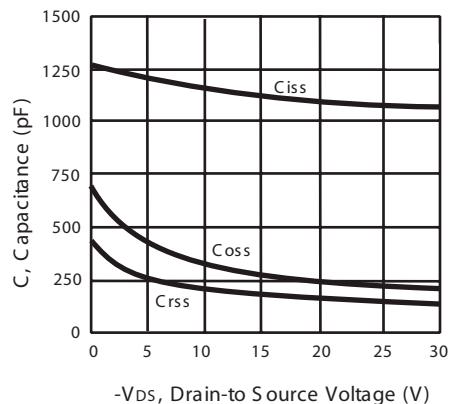


Figure 10. Capacitance

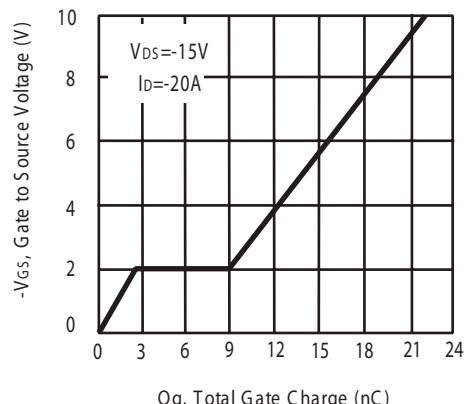


Figure 11. Gate Charge

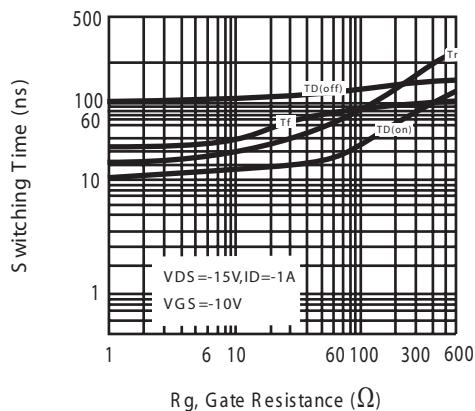


Figure 12. switching characteristics

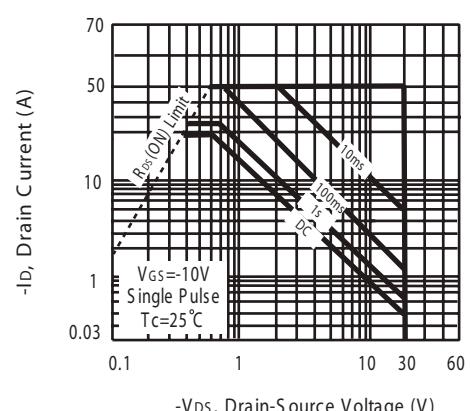


Figure 13. Maximum Safe Operating Area

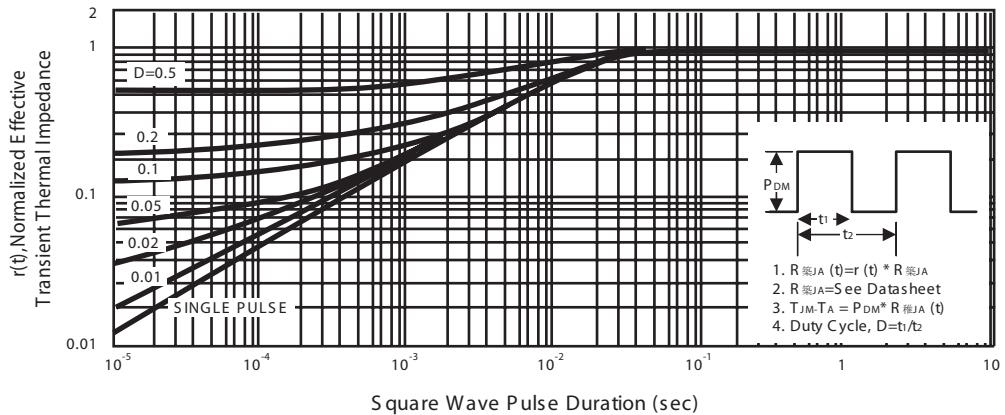
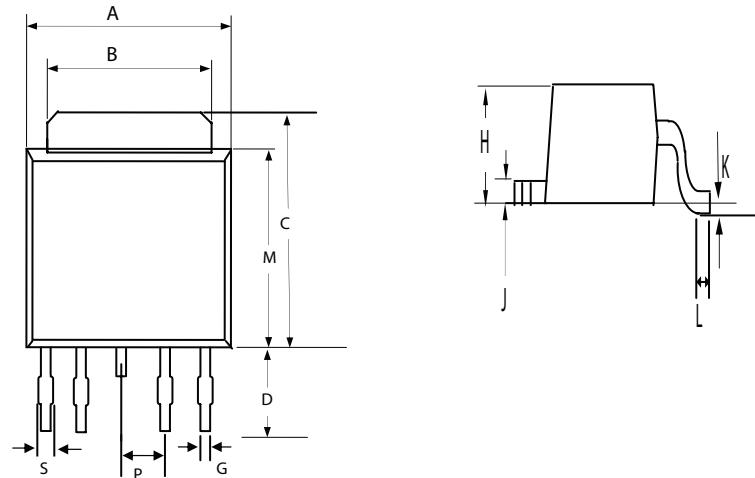


Figure 14. Normalized Thermal Transient Impedance Curve

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PACKAGE OUTLINE DIMENSIONS

TO-252-4L

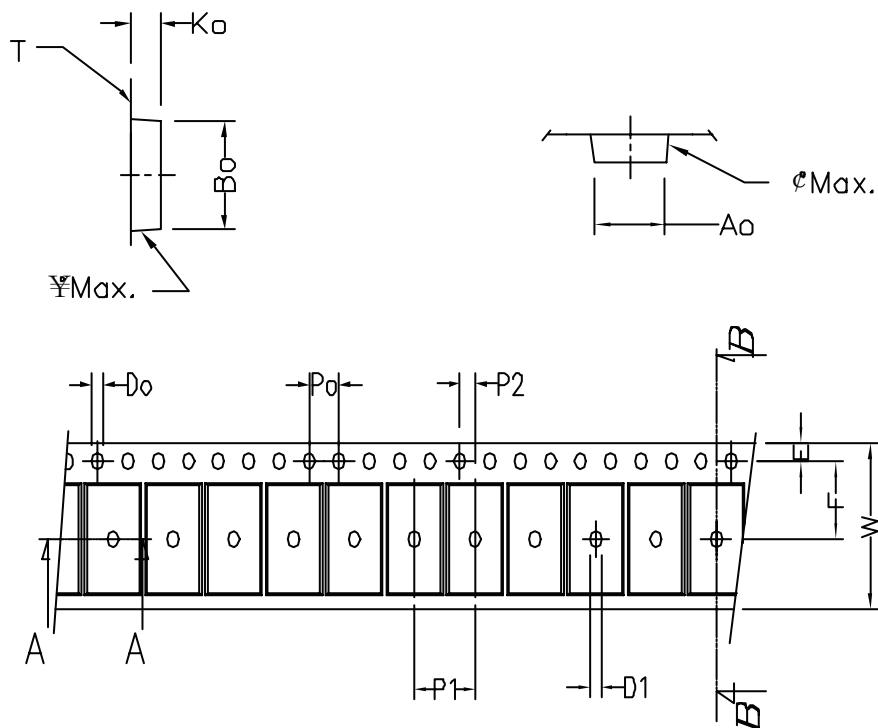


| REF . | Millimeters | |
|-------|-------------|-------|
| | MIN | MAX |
| A | 6.40 | 6.80 |
| B | 5.2 | 5.50 |
| C | 6.80 | 10.20 |
| D | 2.20 | 3.00 |
| P | 1.27 | REF . |
| S | 0.50 | 0.80 |
| G | 0.40 | 0.60 |
| H | 2.20 | 2.40 |
| J | 0.45 | 0.60 |
| K | 0 | 0.15 |
| L | 0.90 | 1.50 |
| M | 5.40 | 5.80 |

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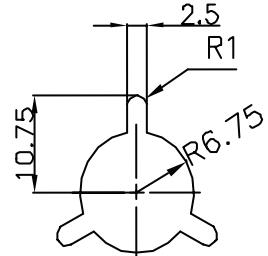
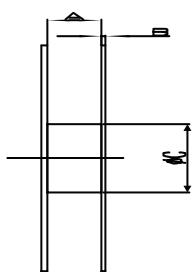
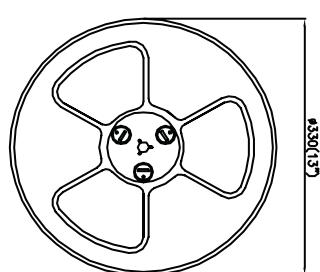
TO-252-4L Tape and Reel Data

TO-252-4L Carrier Tape



| symbol | A_0 | B_0 | K_0 | P_0 | P_1 | P_2 | T |
|--------|----------------|-----------------|-----------------|----------------|----------------------|----------------|------------------|
| Spec | 6.96 ± 0.1 | 10.49 ± 0.1 | 2.79 ± 0.1 | 4.0 ± 0.1 | 8.0 ± 0.10 | 2.0 ± 0.05 | 0.33 ± 0.013 |
| symbol | E | F | D_0 | D_1 | W | $10P_0$ | |
| Spec | 1.75 ± 0.1 | 7.5 ± 0.05 | 1.55 ± 0.05 | 1.5 ± 0.25 | $16.0^{+0.3}_{-0.1}$ | 40.0 ± 0.2 | |

TO-252-4L Reel



UNIT: b

| Width of carrier tape | 8 | 12 | 16 | 24 | 32 | 44 | 56 |
|-----------------------|-----|------|------|------|------|------|------|
| $A \pm 0.1$ | 9.4 | 13.4 | 17.4 | 25.4 | 33.4 | 45.4 | 57.4 |
| B | 2.3 | 2.3 | 2.3 | 2.3 | 2.3 | 2.3 | 2.3 |
| ϕC | 100 | 100 | 100 | 100 | 100 | 100 | 100 |